Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.350 inches
Terminal Length:
1.000 inches
Overall Diameter:
Between 0.195 inches and 0.230 inches
Electrode Internally-electrically Connected To Case:
Cathode
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 reverse voltage, instantaneous
Current Rating Per Characteristic:
500.00 milliamperes forward current, total rms megahertz
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0